#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Mitsushi FUJIKI

Serial Number: Not Yet Assigned

Filed: February 6, 2004 Customer No.: 38834

For: METHOD FOR MANUFACTURING SEMICONDUCTOR DEVICE

#### INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

February 6, 2004

Sir:

In compliance with 37 CFR 1.56, Applicant(s) call(s) to the attention of the Patent and Trademark Office the references listed on the attached PTO-1449.

A copy of each of the references is enclosed herewith.

In the event there are any fees due in connection with the filing of this paper, please charge .

Deposit Account No. 50-2866.

Respectfully submitted, WESTERMAN, HATTORI, DANIELS & ADRIAN, LLP

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Enclosures: PTO-1449; References (2)

Scott M. Daniels

Reg.: 32,562

| INFORMATION DISCLOSURE STATEMENT | N Attv. Docket No. 042068     | Serial No. New Appln.         |  |
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|                                  | Annicont(a), Mitamahi EIIIIII | Applicant(s): Mitsushi FUJIKI |  |
| PTO-1449                         | Filing Date: February 6, 2004 | Group Art Unit:               |  |

## U.S. PATENT DOCUMENTS

| Examiner<br>Initial |    | Document No. | Name | Date | Class | Subclass | Filing Date<br>(If<br>appropriate) |
|---------------------|----|--------------|------|------|-------|----------|------------------------------------|
|                     | AA |              |      |      |       |          |                                    |
|                     | AB |              |      |      |       |          |                                    |
|                     | AC |              |      |      |       |          |                                    |
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|   |    | Document No. | Date     | Country | Translation (Yes or No)           |
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|   | AF |              |          |         |                                   |
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| Examiner |          | Date Considered  |